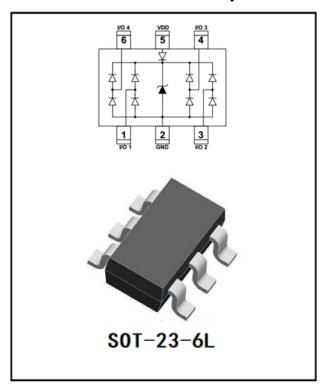






# **Low Capacitance TVS Diode Array**



#### **Features**

•Ultra low capacitance: 0.3Pf typical

◆Ultra low leakage: nA level◆Operating voltage: 5V

Low clamping voltageUp to four data lines and one power line

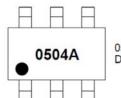
protects
•RoHS Compliant

### **Mechanical Characteristics**

Package: SOT-23 6LLead Finish: Matte Tin

Case Material: "Green" Molding Compound.Moisture Sensitivity: Level 3 per J-STD-020

Marking Information: See Below



0504A = Device Marking Code Dot denotes Pin1

■ **Absolute Maximum Ratings** (Ta=25°C unless otherwise specified)

PARAMETER	SYMBOL	VALUE	UNIT
Operating Temperature Range	TJ	-55 to +125	${\mathbb C}$
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	$^{\circ}$
ESD per IEC 61000-4-2 (Air)	V	±25	KV
ESD per IEC 61000-4-2 (Contact)	$V_{ESD}$	±20	KV
Peak Pulse Power(8/20μs)	P <sub>Pk</sub>	75	W
Peak Pulse Current(8/20µs)	I <sub>PP</sub>	5	А



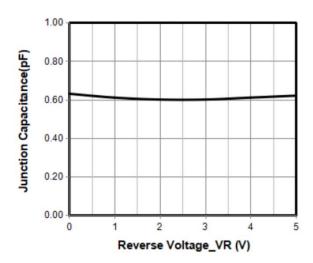
## ESDSLC0504S2

### **■Electrical Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

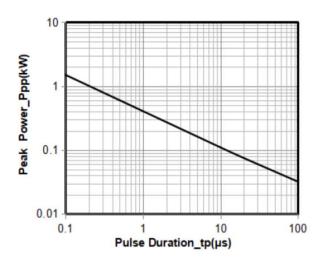
PARAMETER	Symbol	UNIT	Conditions	Min	Тур	Max
Reverse Working Voltage	$V_{\text{RWM}}$	V	Any I/O pin to ground			5
Reverse Leakage Current	I <sub>R</sub>	uA	V <sub>RWM</sub> =5V, any I/O pin to ground			0.5
Breakdown Voltage	$V_{(BR)}$	V	I <sub>T</sub> =1mA, any I/O pin to ground	6		
Forward Voltage	V <sub>F</sub>	V	IF = 15mA			1.2
Clamping Voltage	V <sub>c</sub> ·	V	IPP = 1A (8/20μs pulse), any I/O pin to ground			10
Clamping Voltage	Vc	V	IPP = 5A (8/20µs pulse), any I/O pin to ground			15
Junction Capacitance	CJ	pF	VR = 0V, f = 1MHz, between I/O pins		0.3	0.4
Junction Capacitance	Сл	pF	VR = 0V, f = 1MHz, any I/O pin to ground			0.8

Note 1: I/O pins are Pin 1, 3, 4 and 6

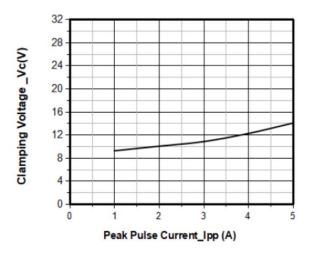
### ■Typical Performance Characteristics (Ta=25°C unless otherwise Specified)



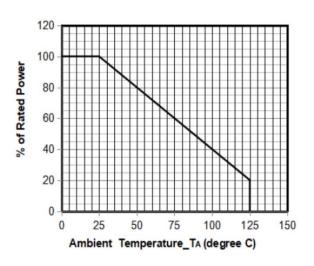
Junction Capacitance vs. Reverse Voltage



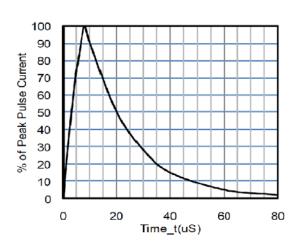
Peak Pulse Power vs. Pulse Time



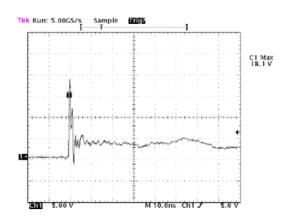
Clamping Voltage vs. Peak Pulse Current



**Power Derating Curve** 

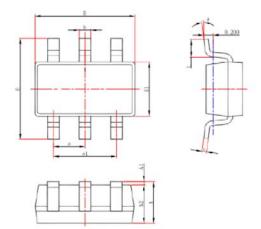


8/20µs waveform per IEC61000-4-5



Note: Data is taken with a 10x attenuator ESD Clamping Voltage 8 kV Contact per IEC61000-4-2

#### **■**SOT-23 6L Package Outline Drawing



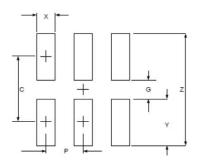
Dimensions		Dimensions In Millimeters	Dimensions	s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037	7(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

3/5



# ESDSLC0504S2

## **■**Suggested Land Pattern



SYM	DIMENSIONS		
	MILLIMETERS	INCHES	
С	2.50	0.098	
G	1.40	0.055	
Р	0.95	0.037	
X	0.60	0.024	
Y	1.10	0.043	
Z	3.60	0.141	



### ESDSLC0504S2

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